



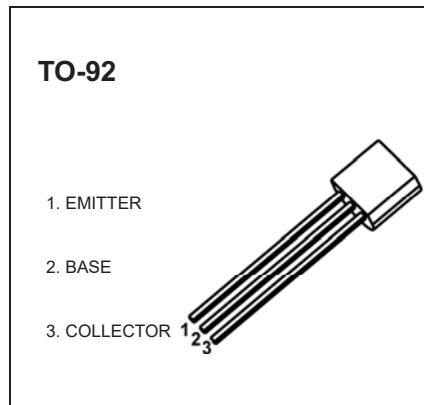
JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

## TO-92 Plastic-Encapsulate Transistors

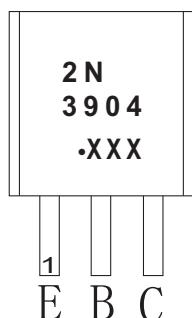
### 2N3904 TRANSISTOR (NPN)

#### FEATURE

- NPN silicon epitaxial planar transistor for switching and Amplifier applications
- As complementary type, the PNP transistor 2N3906 is Recommended
- This transistor is also available in the SOT-23 case with the type designation MMBT3904



#### MARKING

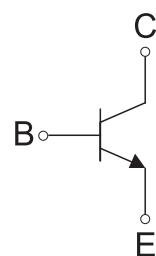


2N3904=Device code

Solid dot=Green molding compound device,  
if none, the normal device

XXX=Code

#### Equivalent Circuit



#### ORDERING INFORMATION

| Part Number | Package | Packing Method | Pack Quantity |
|-------------|---------|----------------|---------------|
| 2N3904      | TO-92   | Bulk           | 1000pcs/Bag   |
| 2N3904-TA   | TO-92   | Tape           | 2000pcs/Box   |

#### MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

| Symbol         | Parameter  | Value   | Unit |
|----------------|--|---------|------|
| $V_{CBO}$      | Collector-Base Voltage                           | 60      | V    |
| $V_{CEO}$      | Collector-Emitter Voltage                        | 40      | V    |
| $V_{EBO}$      | Emitter-Base Voltage                             | 6       | V    |
| $I_C$          | Collector Current -Continuous                    | 0.2     | A    |
| $P_c$          | Collector Power Dissipation                      | 0.625   | W    |
| $T_J, T_{stg}$ | Operation Junction and Storage Temperature Range | -55-150 | °C   |

## ELECTRICAL CHARACTERISTICS

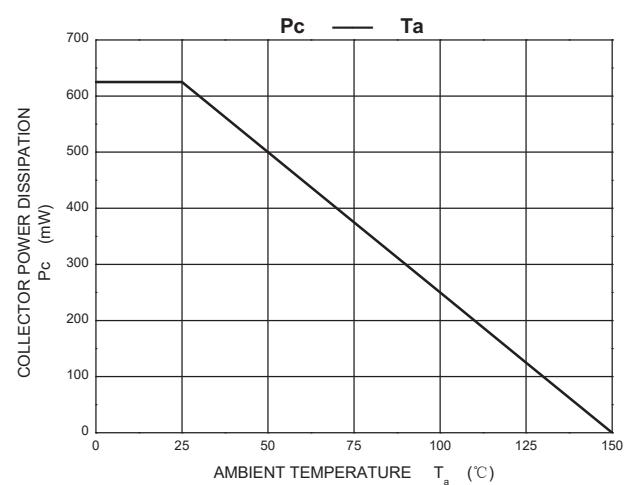
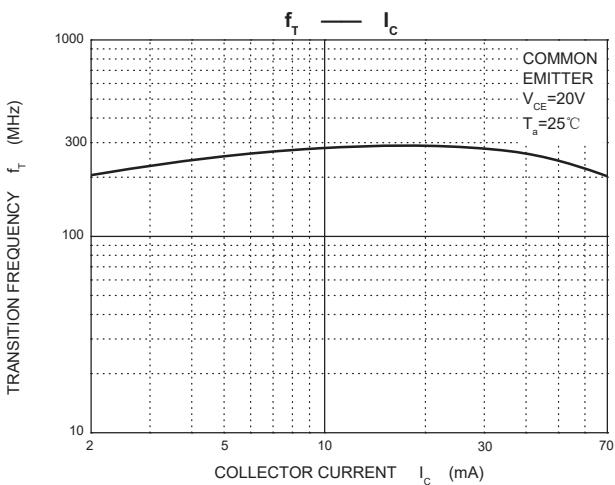
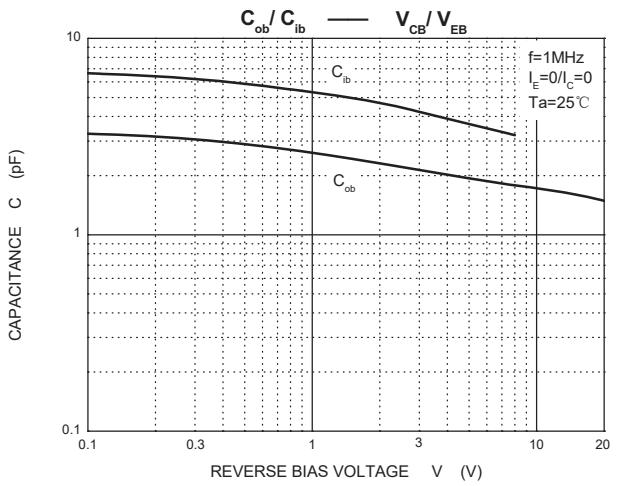
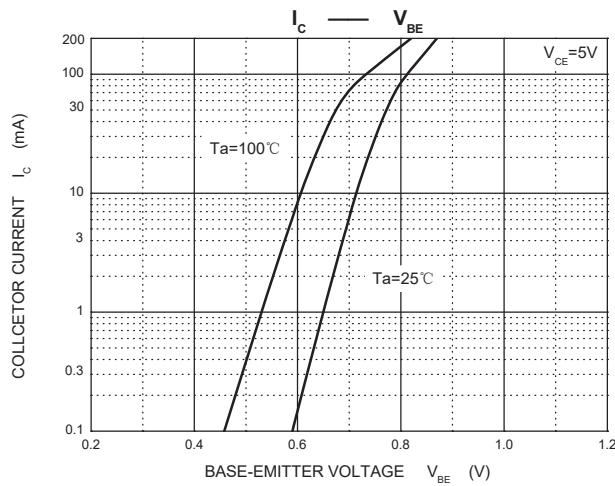
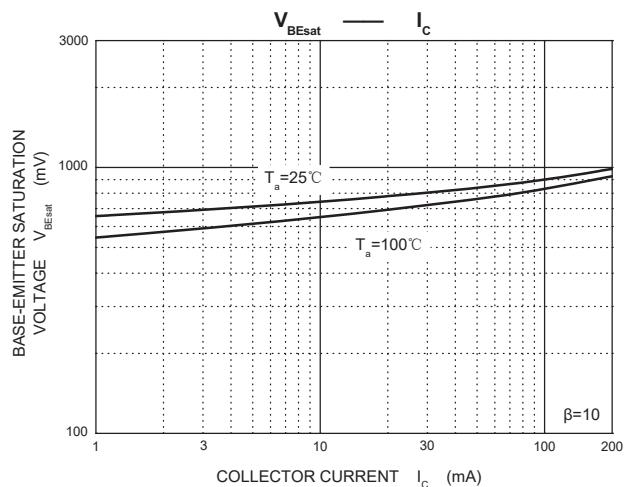
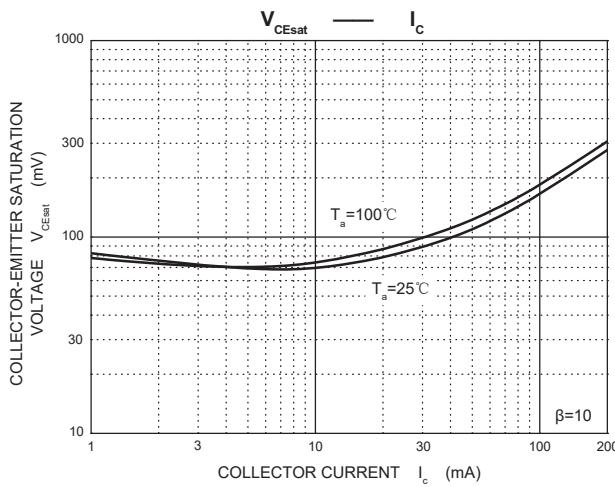
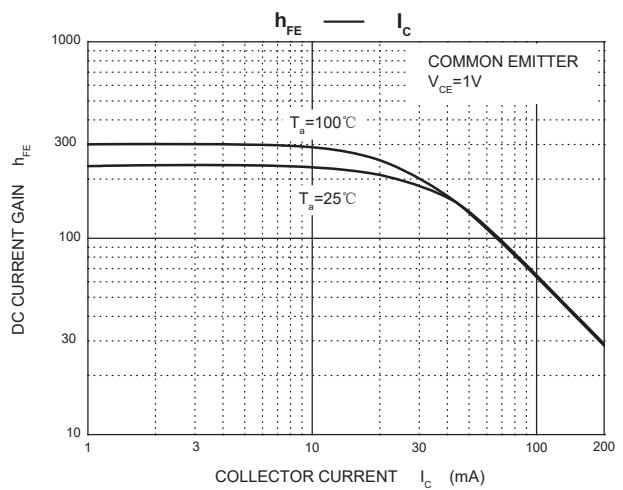
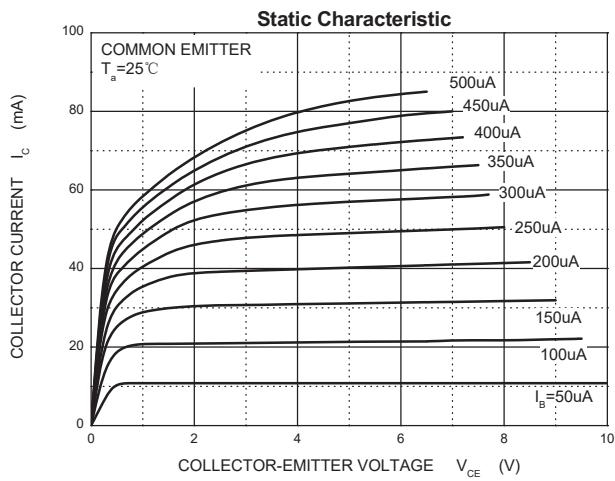
$T_a=25^\circ C$  unless otherwise specified

| Parameter                                   | Symbol        | Test conditions                                     | Min | Typ | Max  | Unit |
|---|---------------|---|-----|-----|------|------|
| <b>Collector-base breakdown voltage</b>     | $V_{(BR)CBO}$ | $I_C=10mA, I_E=0$                                   | 60  |     |      | V    |
| <b>Collector-emitter breakdown voltage</b>  | $V_{(BR)CEO}$ | $I_C=1mA, I_B=0$                                    | 40  |     |      | V    |
| <b>Emitter-base breakdown voltage</b>       | $V_{(BR)EBO}$ | $I_E=10mA, I_C=0$                                   | 6   |     |      | V    |
| <b>Collector cut-off current</b>            | $I_{CBO}$     | $V_{CB}=60V, I_E=0$                                 |     |     | 0.1  | uA   |
| <b>Collector cut-off current</b>            | $I_{CEX}$     | $V_{CE}=30V, V_{EB(off)}=3V$                        |     |     | 0.05 | uA   |
| <b>Emitter cut-off current</b>              | $I_{EBO}$     | $V_{EB}=5V, I_C=0$                                  |     |     | 0.1  | uA   |
| <b>DC current gain</b>                      | $h_{FE1}$     | $V_{CE}=1V, I_C=10mA$                               | 100 |     | 400  |      |
|   | $h_{FE2}$     | $V_{CE}=1V, I_C=50mA$                               | 60  |     |      |      |
|   | $h_{FE3}$     | $V_{CE}=1V, I_C=100mA$                              | 30  |     |      |      |
| <b>Collector-emitter saturation voltage</b> | $V_{CE(sat)}$ | $I_C=50mA, I_B=5mA$                                 |     |     | 0.3  | V    |
| <b>Base-emitter saturation voltage</b>      | $V_{BE(sat)}$ | $I_C=50mA, I_B=5mA$                                 |     |     | 0.95 | V    |
| <b>Transition frequency</b>                 | $f_T$         | $V_{CE}=20V, I_C=10mA, f=100MHz$                    | 300 |     |      | MHz  |
| <b>Delay Time</b>                           | $t_d$         | $V_{CC}=3V, V_{BE}=0.5V,$<br>$I_C=10mA, I_{B1}=1mA$ |     |     | 35   | ns   |
| <b>Rise Time</b>                            | $t_r$         |   |     |     | 35   | ns   |
| <b>Storage Time</b>                         | $t_s$         | $V_{CC}=3V, I_C=10mA$<br>$I_{B1}=I_{B2}=1mA$        |     |     | 200  | ns   |
| <b>Fall Time</b>                            | $t_f$         |   |     |     | 50   | ns   |

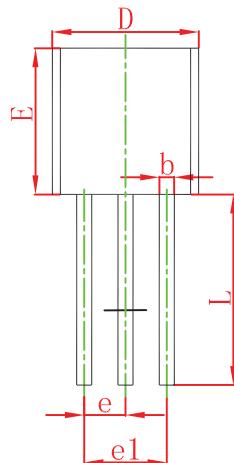
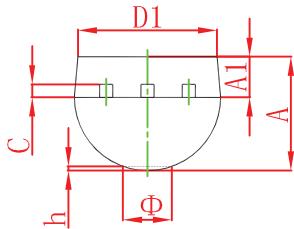
### CLASSIFICATION OF $h_{FE1}$

| Rank  | O       | Y       | G       |
|-------|---------|---------|---------|
| Range | 100-200 | 200-300 | 300-400 |

# Typical Characteristics

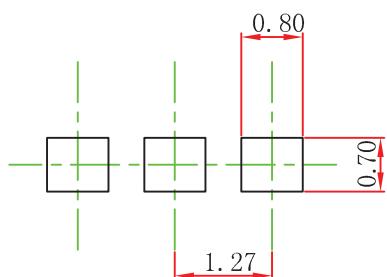


## TO-92 Package Outline Dimensions



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min                       | Max    | Min                  | Max   |
| A      | 3.300                     | 3.700  | 0.130                | 0.146 |
| A1     | 1.100                     | 1.400  | 0.043                | 0.055 |
| b      | 0.380                     | 0.550  | 0.015                | 0.022 |
| c      | 0.360                     | 0.510  | 0.014                | 0.020 |
| D      | 4.300                     | 4.700  | 0.169                | 0.185 |
| D1     | 3.430                     |        | 0.135                |       |
| E      | 4.300                     | 4.700  | 0.169                | 0.185 |
| e      | 1.270 TYP                 |        | 0.050 TYP            |       |
| e1     | 2.440                     | 2.640  | 0.096                | 0.104 |
| L      | 14.100                    | 14.500 | 0.555                | 0.571 |
| K      |                           | 1.600  |                      | 0.063 |
| h      | 0.000                     | 0.380  | 0.000                | 0.015 |

## TO-92 Suggested Pad Layout



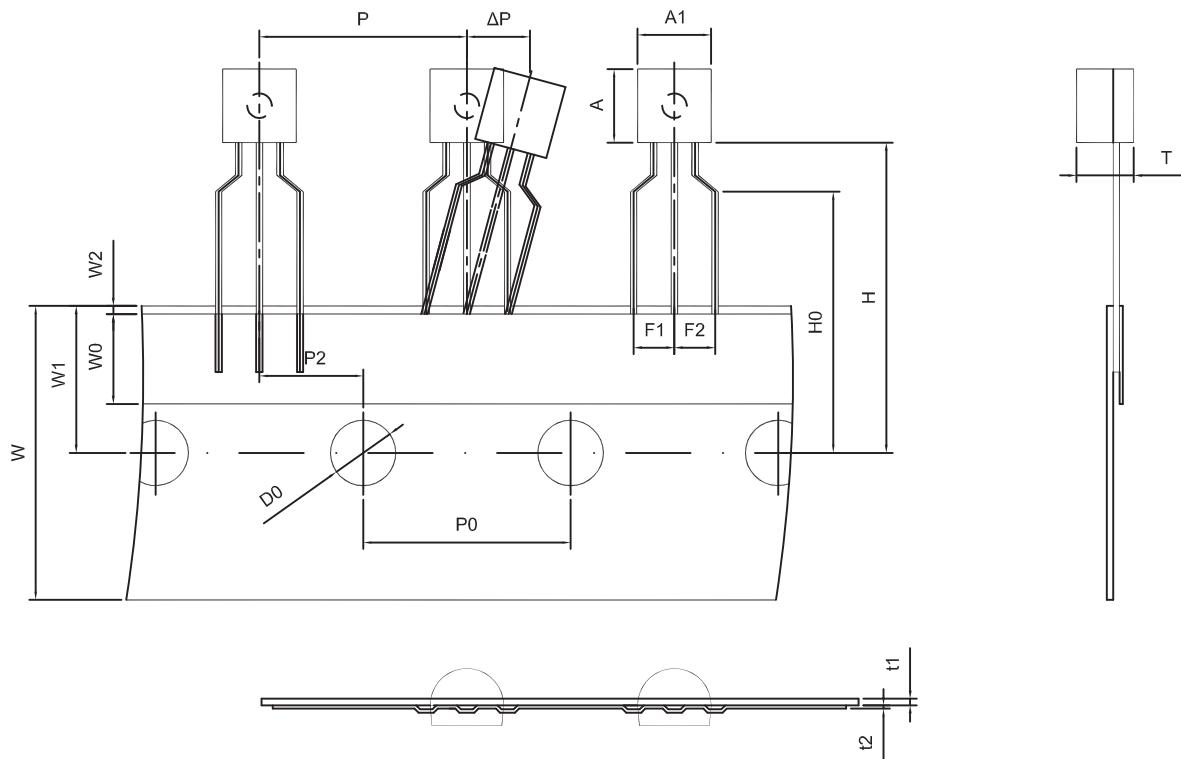
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$ mm.
3. The pad layout is for reference purposes only.

### NOTICE

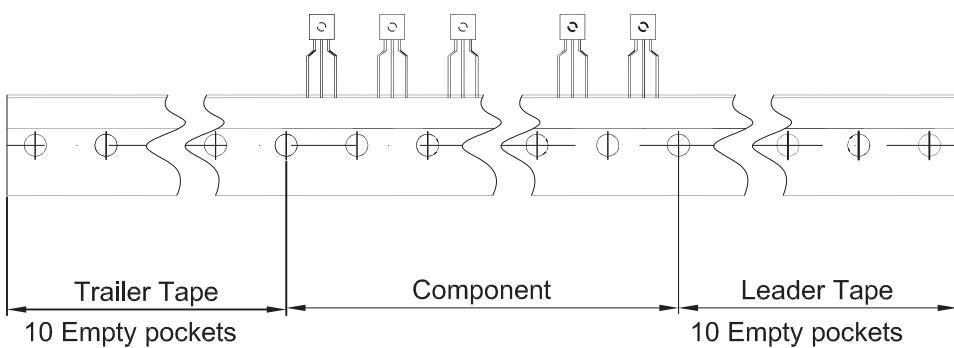
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## TO-92 Tape and Reel



Dimensions are in millimeter

| A1  | A   | T        | P    | P0   | P2   | F1  | F2  | W    |
|-----|-----|----------|------|------|------|-----|-----|------|
| 4.5 | 4.5 | 3.5      | 12.7 | 12.7 | 6.35 | 2.5 | 2.5 | 18.0 |
| W0  | W1  | W2       | H    | H0   | D0   | t1  | t2  | ΔP   |
| 6.0 | 9.0 | 1.0 MAX. | 19.0 | 16.0 | 4.0  | 0.4 | 0.2 | 0    |



| Package | Box      | Box Size(mm) | Carton     | Carton Size(mm) |
|---------|----------|--------------|------------|-----------------|
| TO-92   | 2000 pcs | 333×162×43   | 20,000 pcs | 350×340×250     |

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